## NSN 5961-01-333-6200

No Fiig: A110a0



Transistor - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-01-333-6200 **Inclosure Material:** Plastic **Overall Length:** Between 0.170 inches and 0.210 inches **Terminal Length:** 0.500 inches **Overall Height:** Between 0.125 inches and 0.165 inches **Overall Width:** Between 0.175 inches and 0.205 inches **Function For Which Designed:** Switching **End Application:** 5865-01-188-3309 an/ulq-1 (v) 1 jammer system respo **Internal Configuration:** Field effect Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-92 **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: -3.0 gate to source cutoff voltage and -25.0 breakdown voltage, gate-to-source, with all other terminals short-circuited to source and -25.0 gate to source voltage **Current Rating Per Characteristic:** 15.00 milliamperes zero-gate-voltage drain current and 10.00 milliamperes gate current **Power Rating Per Characteristic:** 360.0 milliwatts total power dissipation **Maximum Operating Tempurature Per Measurement Point:** 135.0 degrees celsius ambient air **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**